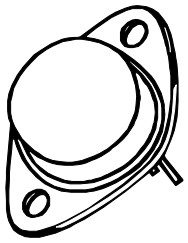
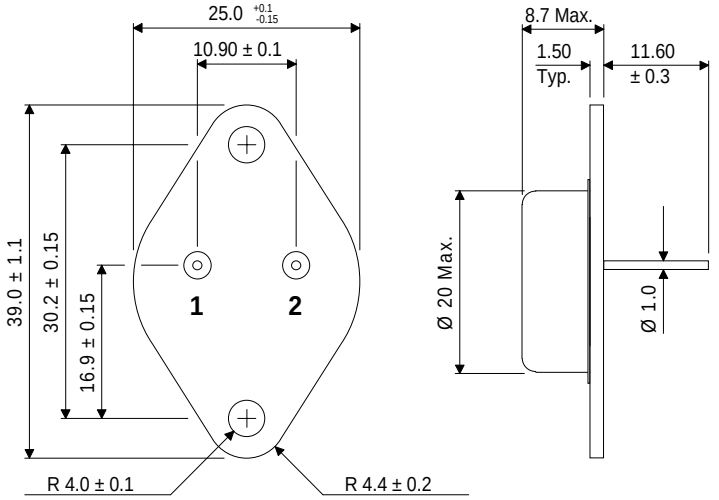
MAGNA TEC



BUZ905
BUZ906

MECHANICAL DATA
Dimensions in mm

P–CHANNEL POWER MOSFET



TO–3

Pin 1 – Gate Pin 2 – Drain Case – Source

POWER MOSFETS FOR AUDIO APPLICATIONS

FEATURES

- **HIGH SPEED SWITCHING**
- **P–CHANNEL POWER MOSFET**
- **SEMEFAB DESIGNED AND DIFFUSED**
- **HIGH VOLTAGE (160V & 200V)**
- **HIGH ENERGY RATING**
- **ENHANCEMENT MODE**
- **INTEGRAL PROTECTION DIODE**
- **N–CHANNEL ALSO AVAILABLE AS BUZ900 & BUZ901**

ABSOLUTE MAXIMUM RATINGS

(T_{case} = 25°C unless otherwise stated)

			BUZ905	BUZ906
V_{DSX}	Drain – Source Voltage		-160V	-200V
V_{GSS}	Gate – Source Voltage		±14V	
I_D	Continuous Drain Current		-8A	
$I_{D(PK)}$	Body Drain Diode		-8A	
P_D	Total Power Dissipation	@ T_{case} = 25°C	125W	
T_{stg}	Storage Temperature Range		–55 to 150°C	
T_j	Maximum Operating Junction Temperature		150°C	
$R_{\theta JC}$	Thermal Resistance Junction – Case		1.0°C/W	

MAGNA TEC

BUZ905
BUZ906

STATIC CHARACTERISTICS (T_{case} = 25°C unless otherwise stated)

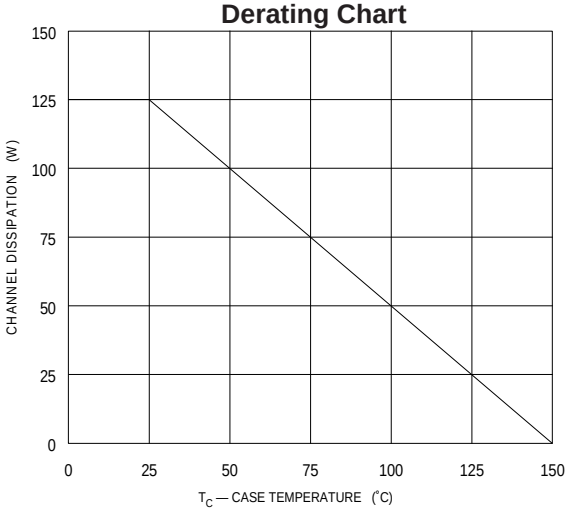
	Characteristic	Test Conditions		Min.	Typ.	Max.	Unit
BV_{DSX}	Drain – Source Breakdown Voltage	V_{GS} = 10V I_D = -10mA	BUZ905	-160			V
			BUZ906	-200			
BV_{GSS}	Gate – Source Breakdown Voltage	V_{DS} = 0	I_G = ±100µA	±14			V
$V_{GS(OFF)}$	Gate – Source Cut–Off Voltage	V_{DS} = -10V	I_D = -100mA	-0.15		-1.5	V
$V_{DS(SAT)}$*	Drain – Source Saturation Voltage	V_{GD} = 0	I_D = -8A			-12	V
I_{DSX}	Drain – Source Cut–Off Current	V_{GS} = -10V	V_{DS} = -160V BUZ905			-10	mA
			V_{DS} = -200V BUZ906			-10	
yfs*	Forward Transfer Admittance	V_{DS} = -10V	I_D = -3A	0.7		2	S

DYNAMIC CHARACTERISTICS (T_{case} = 25°C unless otherwise stated)

	Characteristic	Test Conditions	Min.	Typ.	Max.	Unit
C_{iss}	Input Capacitance	V_{DS} = -10V f = 1MHz		734		pF
C_{oss}	Output Capacitance			300		
C_{rss}	Reverse Transfer Capacitance			26		
t_{on}	Turn–on Time	V_{DS} = -20V I_D = -5A		120		ns
t_{off}	Turn-off Time			60		

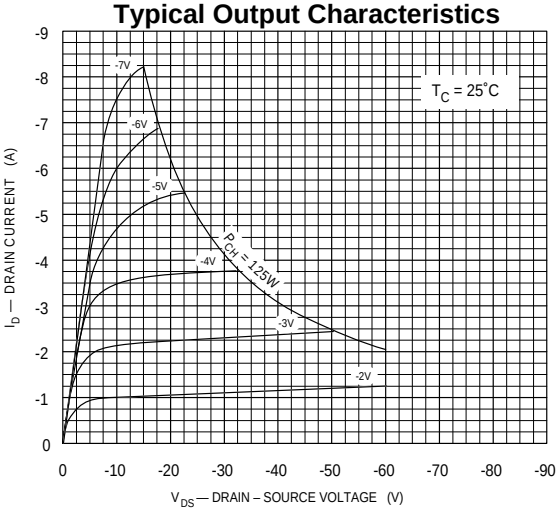
* Pulse Test: Pulse Width = 300µs , Duty Cycle ≤ 2%.

Derating Chart

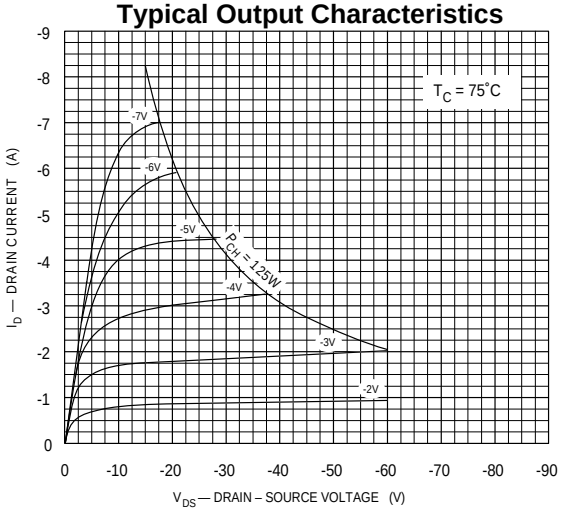


BUZ905
BUZ906

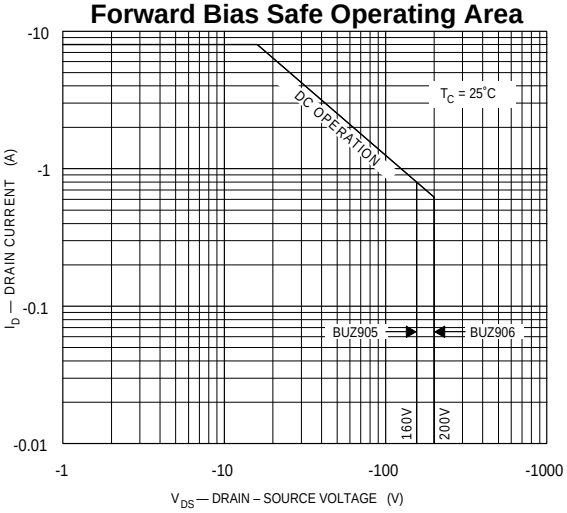
Typical Output Characteristics



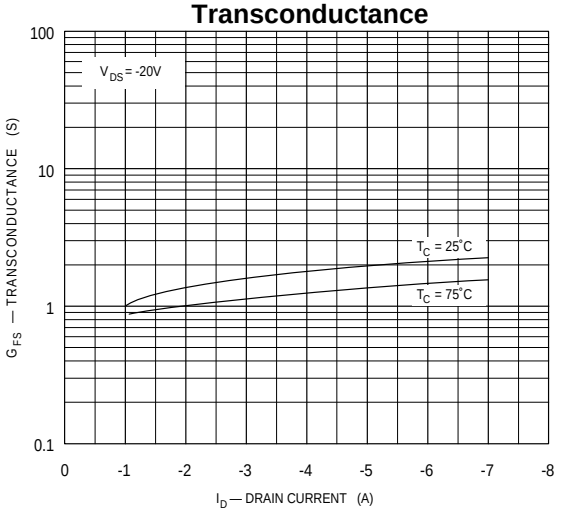
Typical Output Characteristics



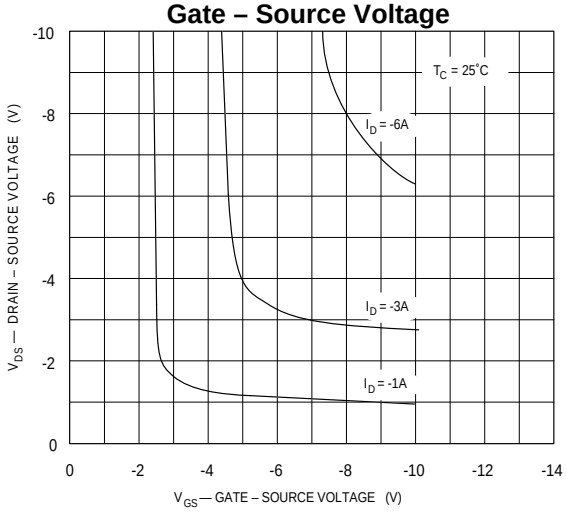
Forward Bias Safe Operating Area



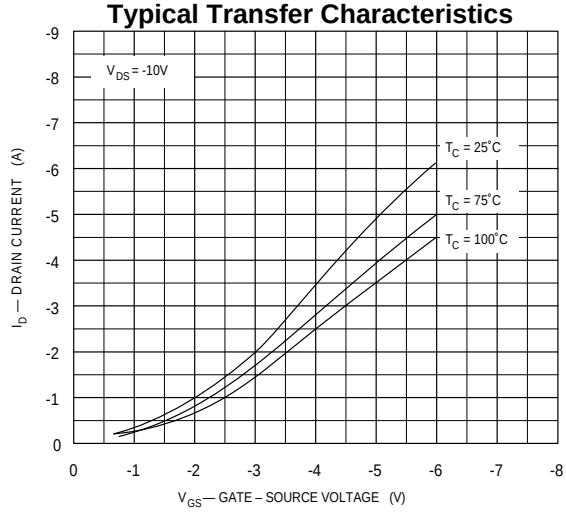
Transconductance



Drain – Source Voltage vs Gate – Source Voltage



Typical Transfer Characteristics



MAGNA TEC

BUZ905
BUZ906